# MMIC Amplifier, 5 V, 22.7 mA, 0.1 to 3 GHz, MCPH6

# Product Preview NSVG3117SG6

# Features

- High Gain: Gp = 33.5 dB typ. @ 2.2 GHz
- Wideband Response: fu = 3.0 GHz
- Low Current:  $I_{CC} = 22.7$  mA typ.
- High Output Power: Po (1 dB) = 5.7 dBm
- Port Impedance: Input/Output: 50 Ω
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- This is a Pb–Free Device

# ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Symbol	Parameter	Ratings	Unit
V <sub>CC</sub>	Supply Voltage	6	V
Icc	Circuit Current	40	mA
PD	Allowable Power Dissipation	280	mW
Topr	Operating Temperature	-40 to +85	°C
Tstg	Storage Temperature	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### **RECOMMENDED OPERATING CONDITIONS** (Ta = 25°C)

		Ratings			
Symbol	Parameter	Min	Тур	Max	Unit
V <sub>CC</sub>	Supply Voltage	4.5	5	5.5	V
Topr	Operating Ambient Temperature	-40	+25	+125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.



# **ON Semiconductor®**

www.onsemi.com



SC-88FL / MCPH6 CASE 419AS

# MARKING DIAGRAM



HLG = Specific Device Code

M = Date Code

= Pb-Free Package

# ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.

# NSVG3117SG6

			Ratings			
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CC</sub>	Circuit Current		18.5	22.7	28.0	mA
Gp	Power Gain	f = 1 GHz	29.5	31.2	32.5	dB
		f = 2.2 GHz	30.5	33.5	35.5	
ISL	Isolation	f = 1 GHz	35.0	37.6	-	dB
		f = 2.2 GHz	34.0	36.5	-	
RLin	Input Return Loss	f = 1 GHz	9.0	11.2	-	dB
		f = 2.2 GHz	4.5	6.0	-	
RLout	Output Return Loss	f = 1 GHz	11.0	14.3	-	dB
		f = 2.2 GHz	12.0	16.3	-	
NF	Noise Figure	f = 1 GHz	-	4.1	5.0	dB
		f = 2.2 GHz	-	3.9	5.0	
Po (1dB)	Gain 1dB Compression Output Power	f = 1 GHz	7.5 9.8		-	dBm
	(Note 2)	f = 2.2 GHz	3.7	5.7	-	
fu	Upper Limit Operating Frequency (Note 2)	3 dB down below flat gain at f = 1GHz	-	3.0	-	GHz

# **ELECTRICAL CHARACTERISTICS** (Ta = 25°C, $V_{CC}$ = 5 V, Zs = Z<sub>L</sub> = 50 $\Omega$ )

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product Product parameter performance for indicated in the Electrical Characteristics for the listed test conditions, unless otherwise performance may not be indicated by the Electrical Characteristics if operated under different conditions.
Pay attention to handling since it is liable to be affected by static electricity due to the high frequency process adopted.
On evaluation board.

# **Test Circuit**



Figure 1. Test Circuit

# **Evaluation Board**



Symbol	Value
C1, C2	100 pF
C3	1000 pF
L1	100 nH

Figure 2. Evaluation Board

Characteristics







# NSVG3117SG6

#### S Parameter





#### **ORDERING INFORMATION**

Device Order Number	Specific Device Marking	Package Type (JEITA, JEDEC)	Package Type	Shipping <sup>†</sup>
NSVG3117SG6T1G	HLG	SC-88FL (Pb-Free/Halogen Free)	MCPH6 (Pb–Free/Halogen Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





ON Semiconductor and ()) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.